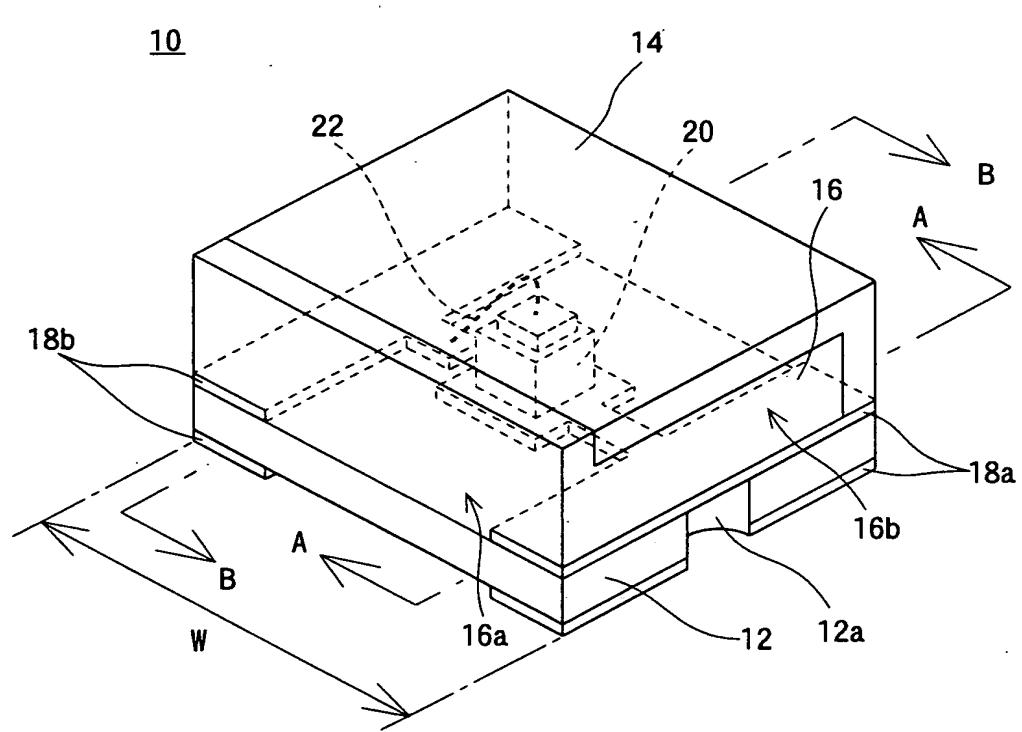
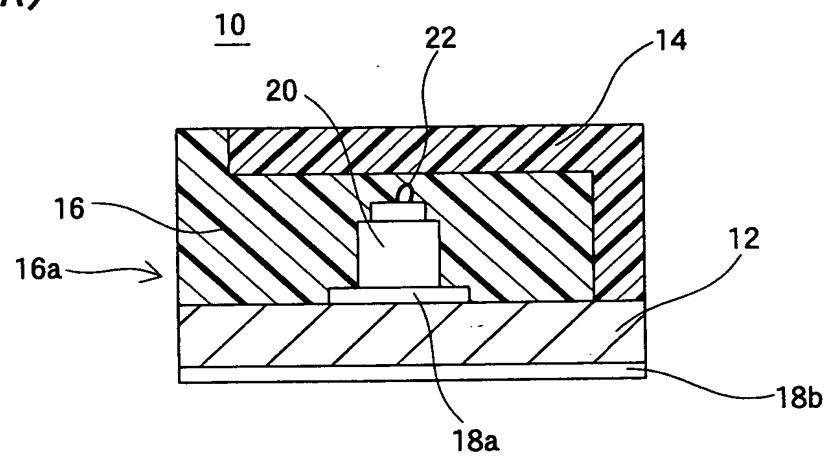


FIG. 1



**FIG. 2(A)**



**FIG. 2(B)**

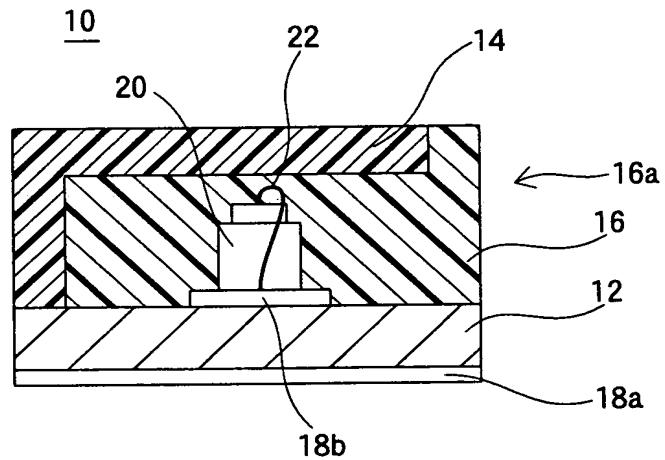


FIG. 3(A)

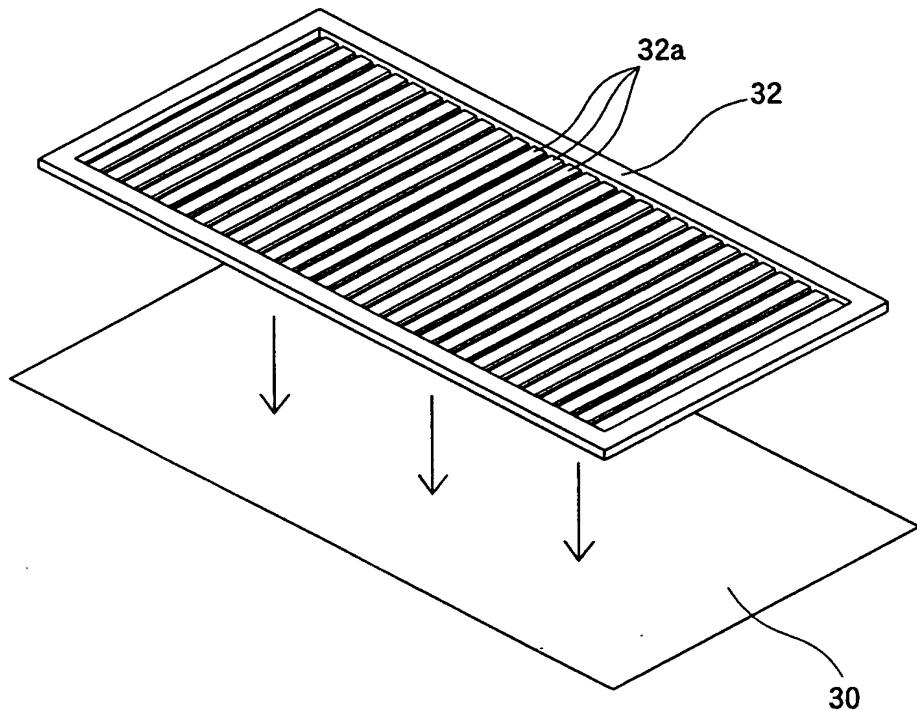


FIG. 3(B)

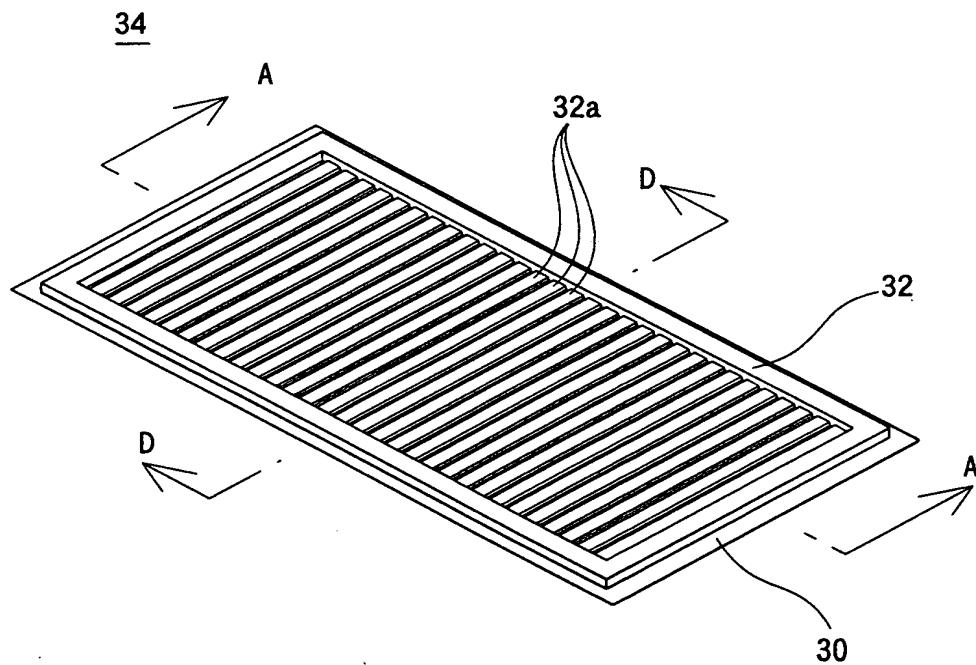


FIG. 4(A)

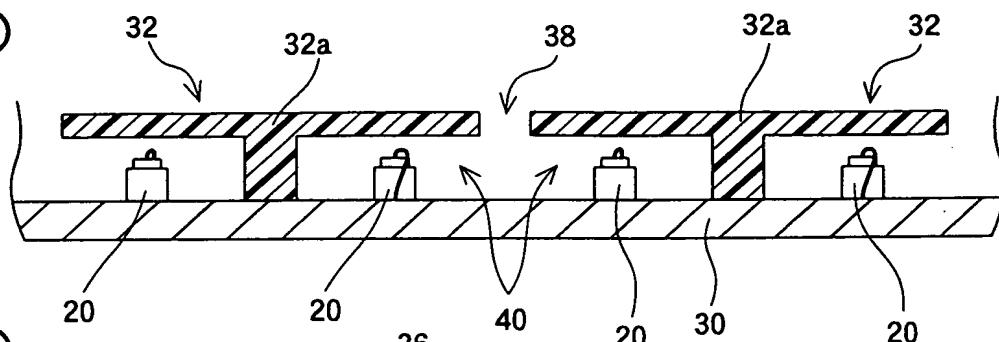


FIG. 4(B)

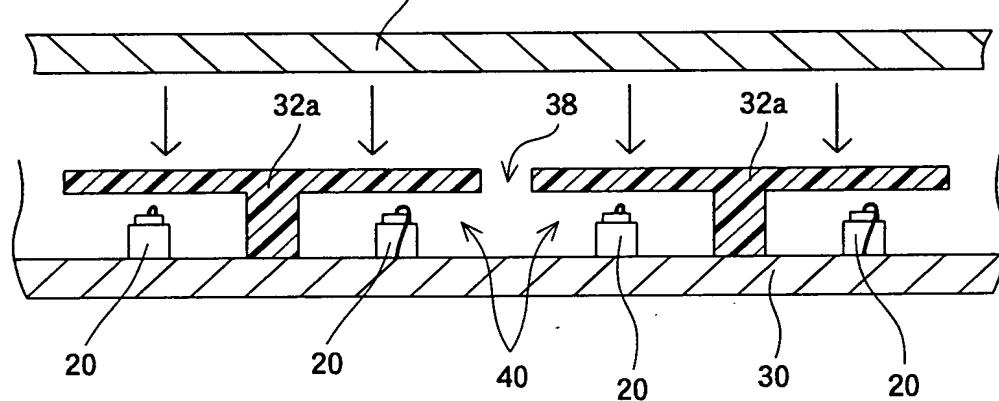


FIG. 4(C)

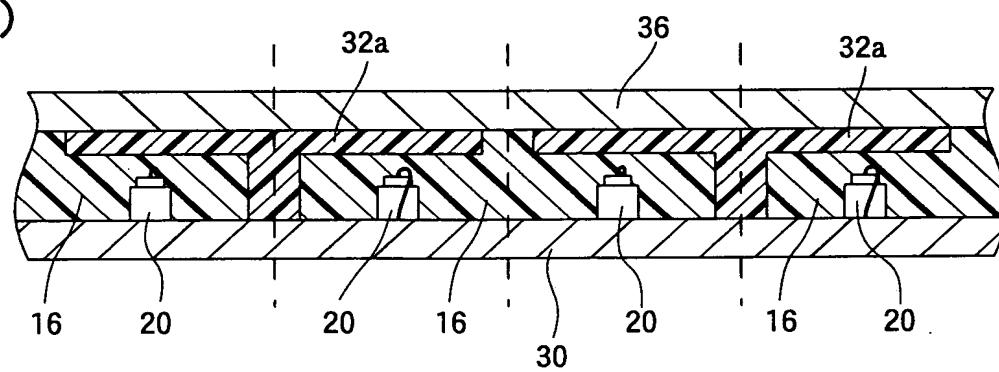


FIG. 4(D)

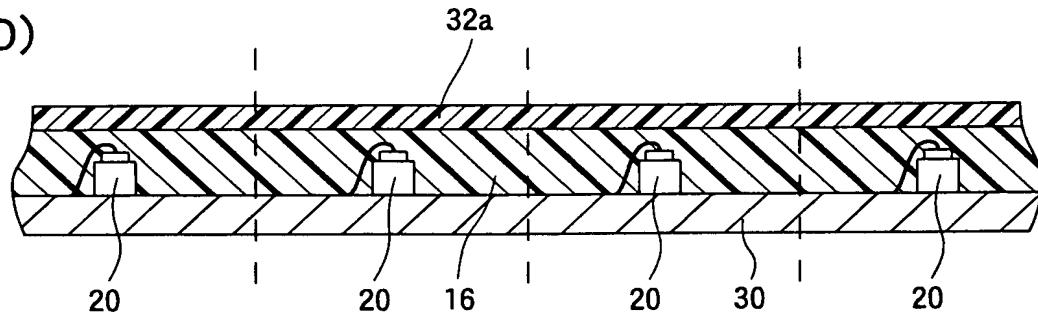


FIG. 5

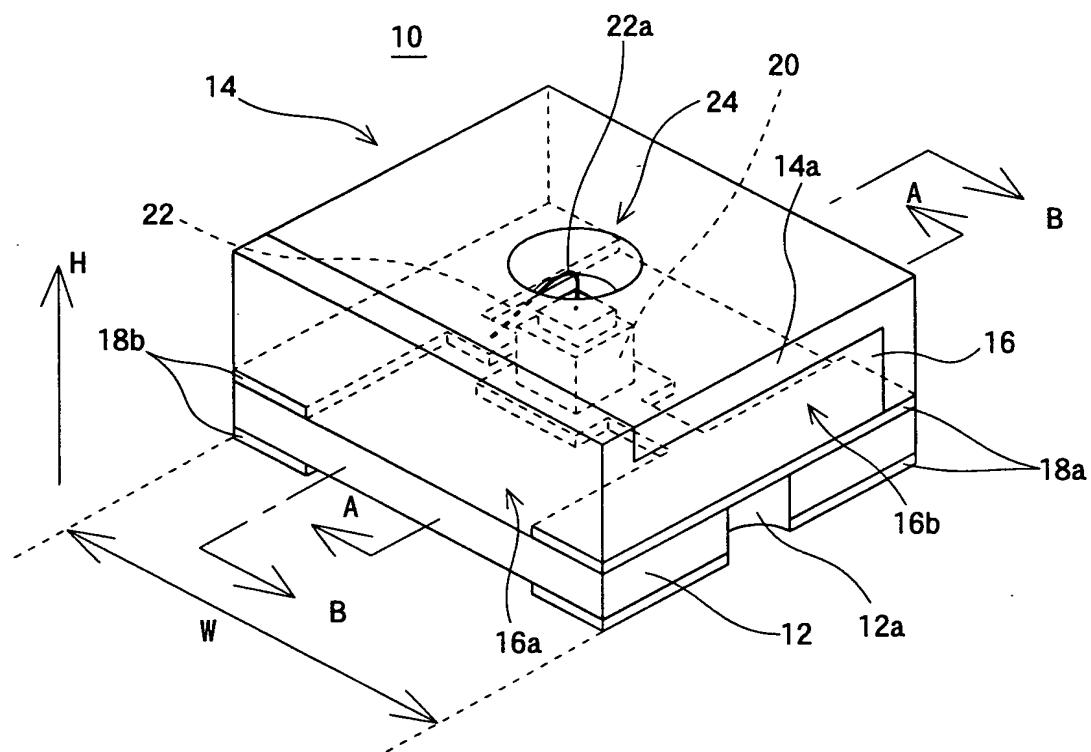


FIG. 6(A)

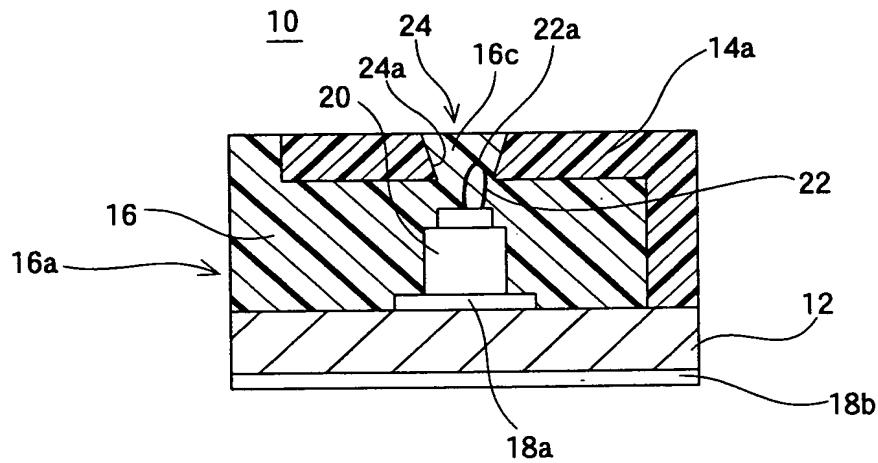


FIG. 6(B)

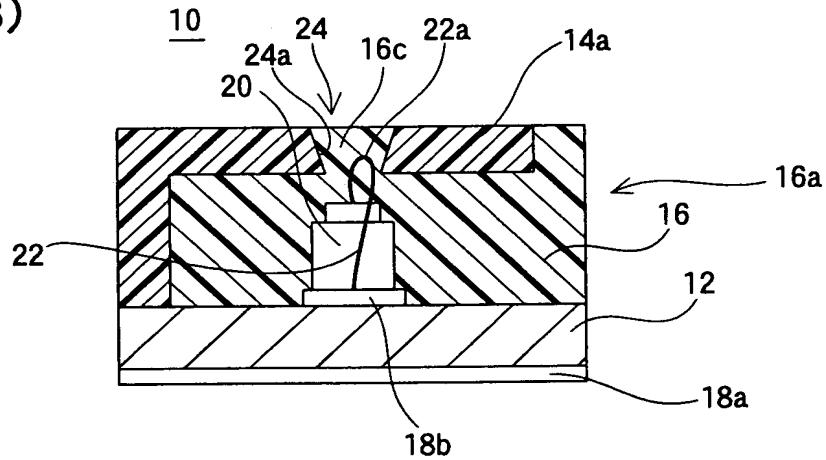


FIG. 7(A)

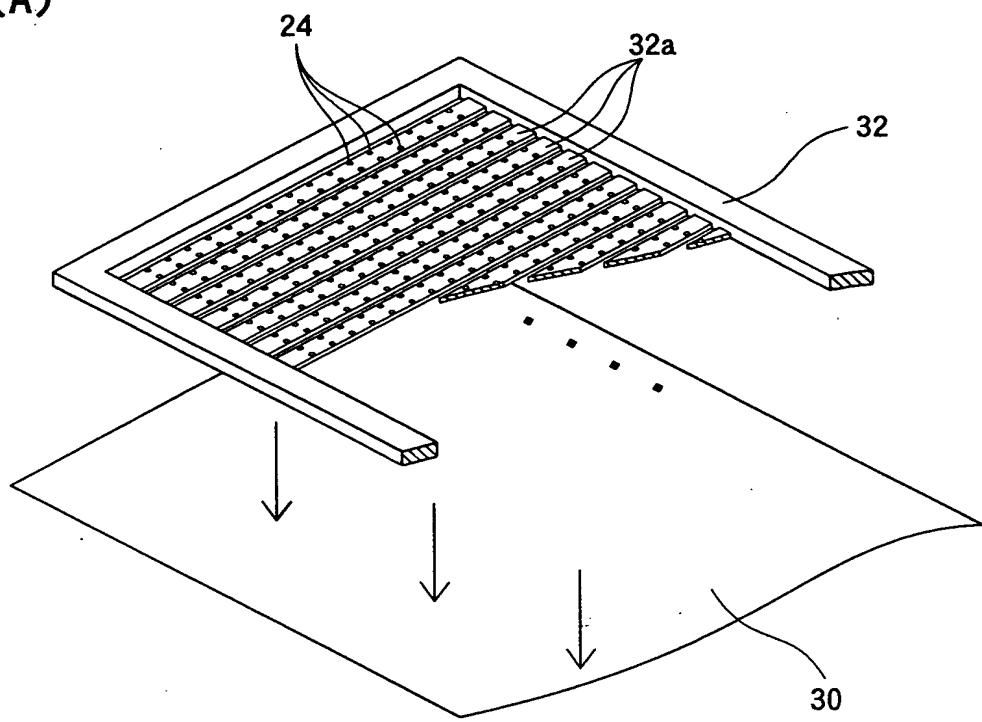


FIG. 7(B)

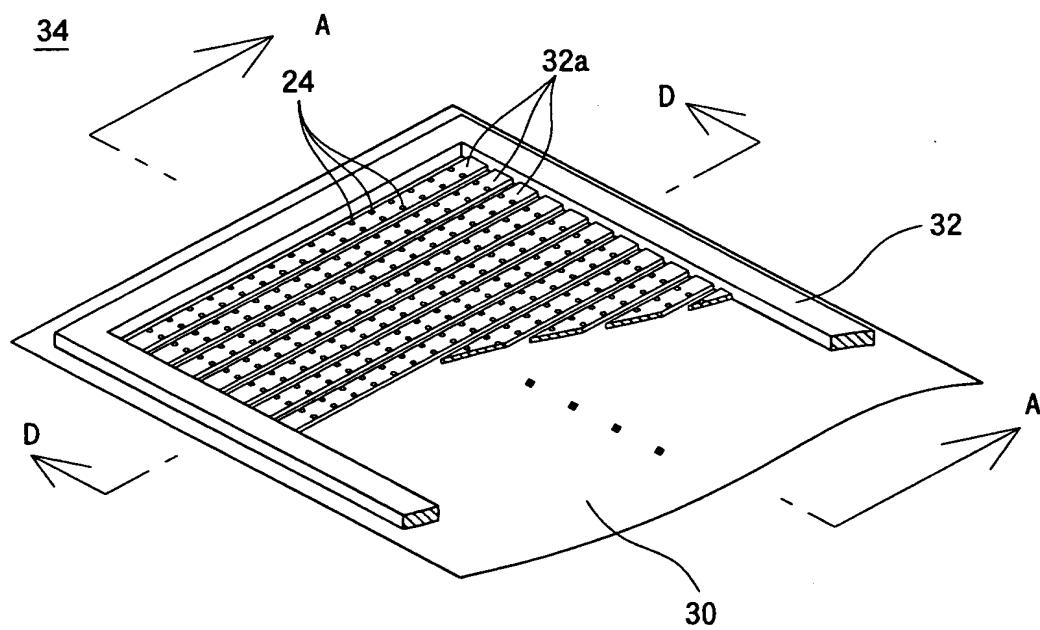


FIG. 8(A)

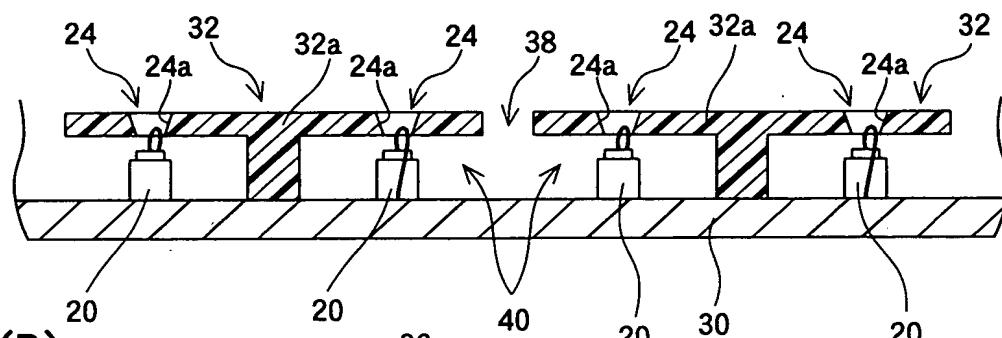


FIG. 8(B)

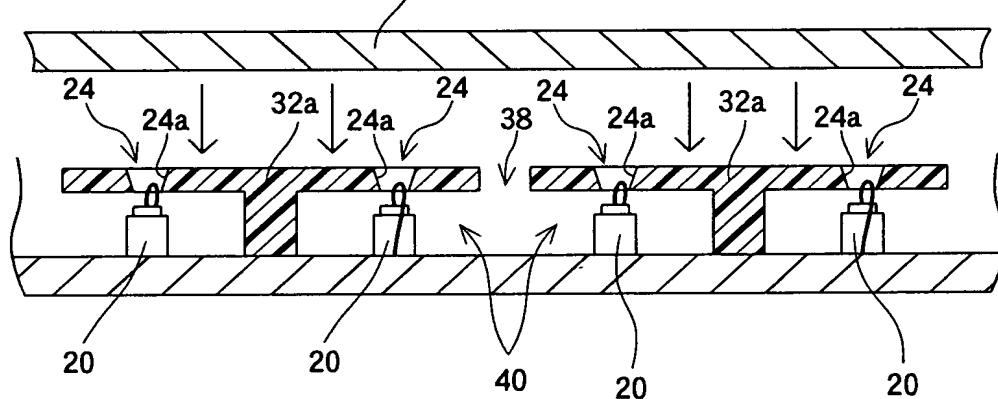


FIG. 8(C)

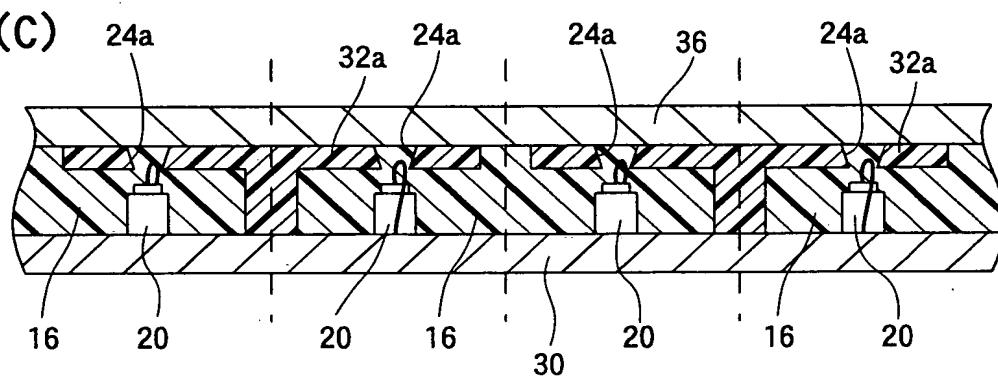


FIG. 8(D)

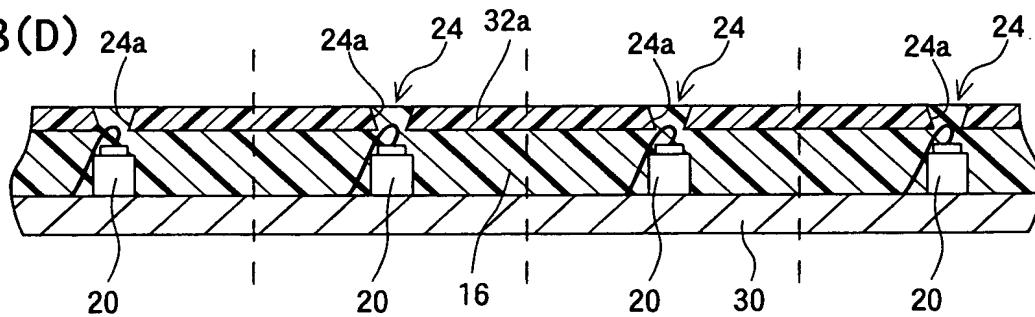


FIG. 9

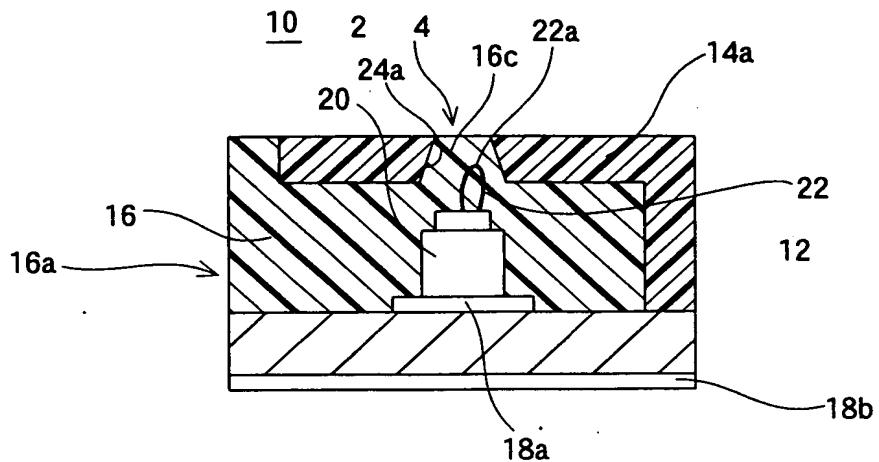


FIG. 10

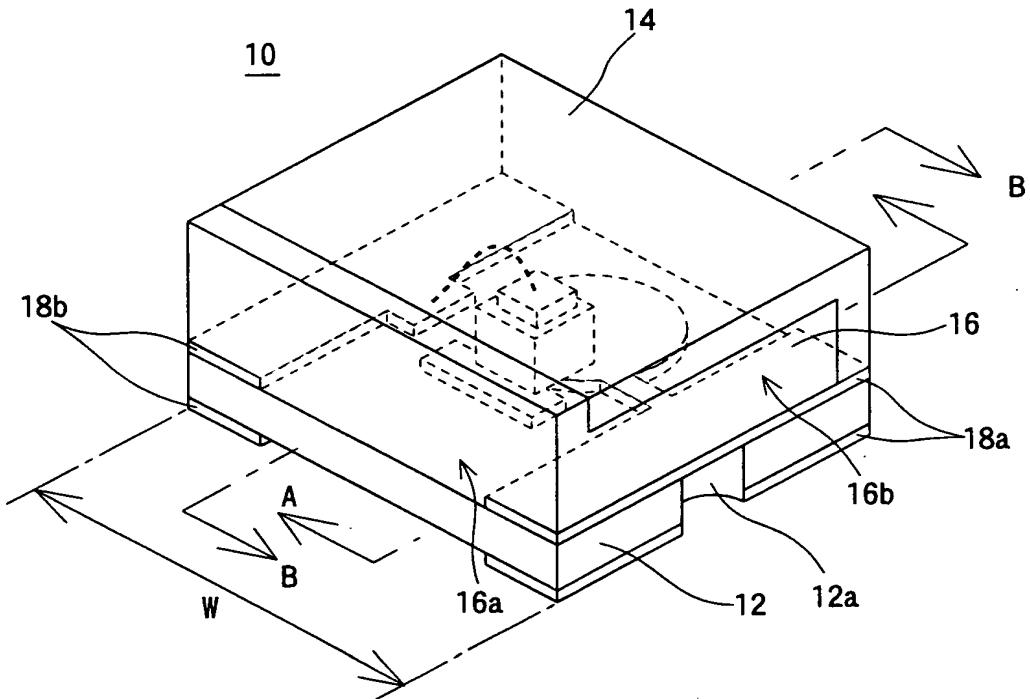


FIG. 11(A)

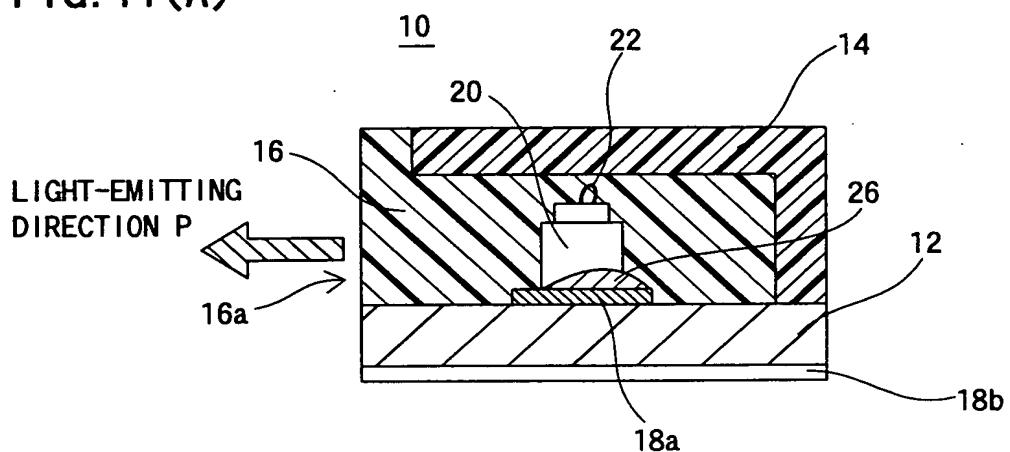


FIG. 11(B)

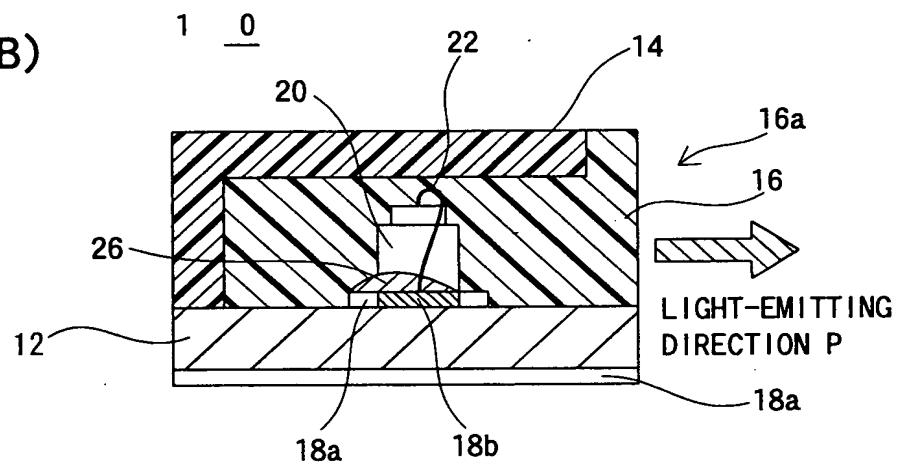


FIG. 12

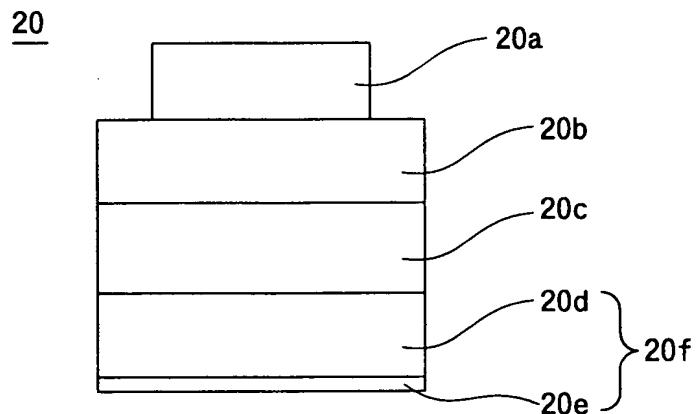


FIG. 13(A)

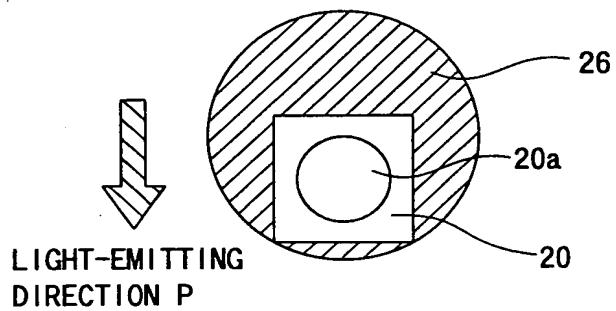


FIG. 13(B)

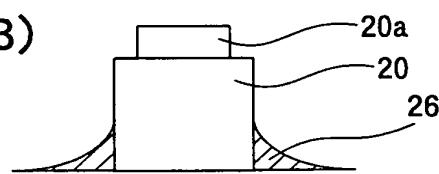


FIG. 13(C)

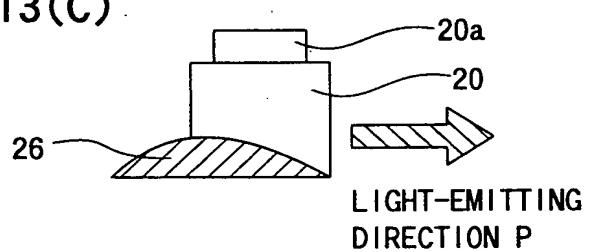


FIG. 13(D)

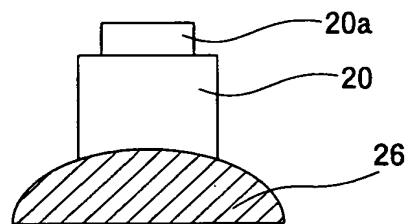


FIG. 14(A)

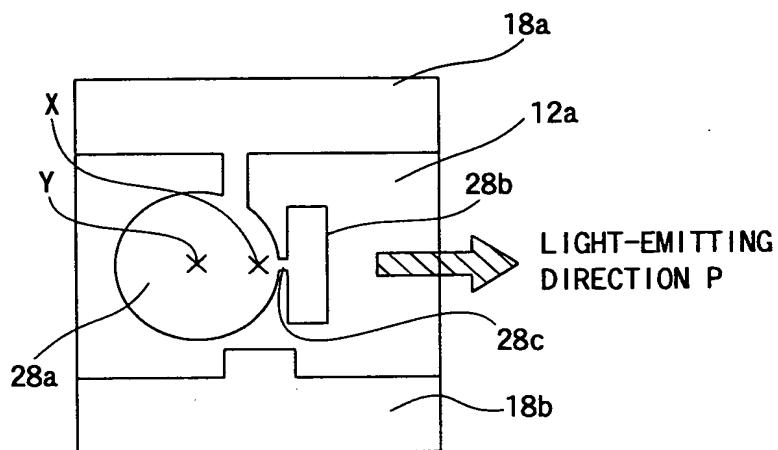
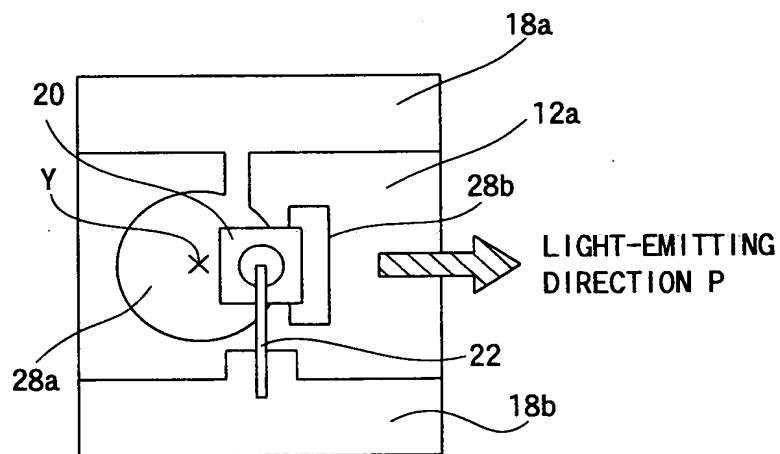


FIG. 14(B)



Title: Side-Emission Type Semiconductor Light-Emitting Device and Manufacturing Method  
hereof  
Inventor: Takehiro Fujii  
Docket No.: 362-59 PCT/US  
Express Mailing No.: EL608295130 US

FIG. 15(A)

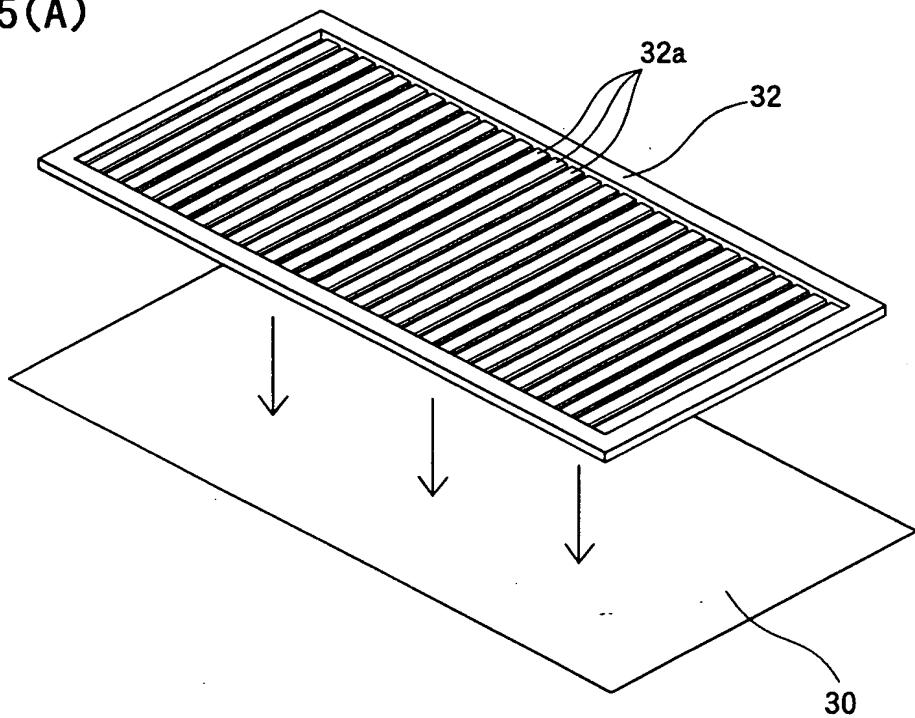
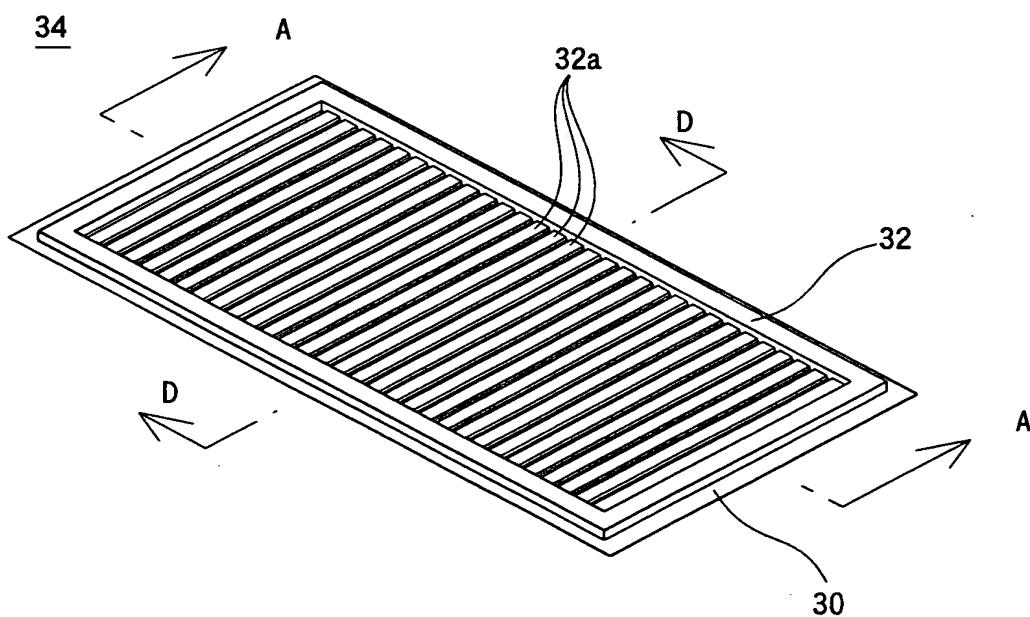


FIG. 15(B)



Title: Side-Emission Type Semiconductor Light-Emitting Device and Manufacturing Method  
thereof  
Inventor: Takehiro Fujii  
Docket No.: 362-59 PCT/US  
Express Mailing No.: EL608295130 US

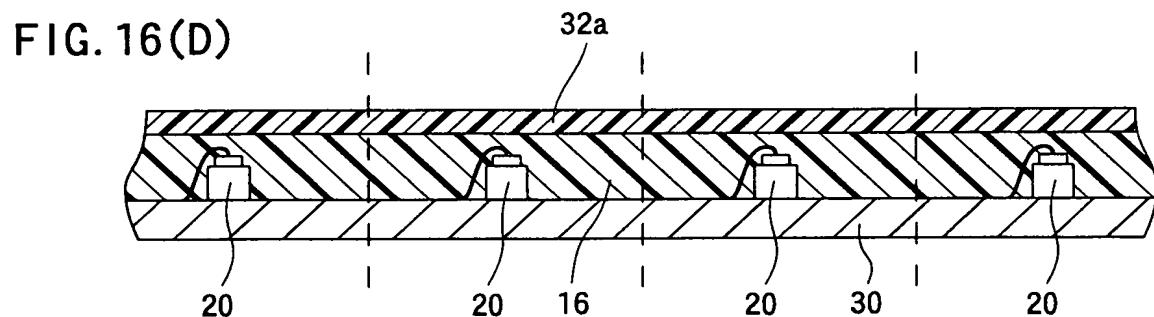
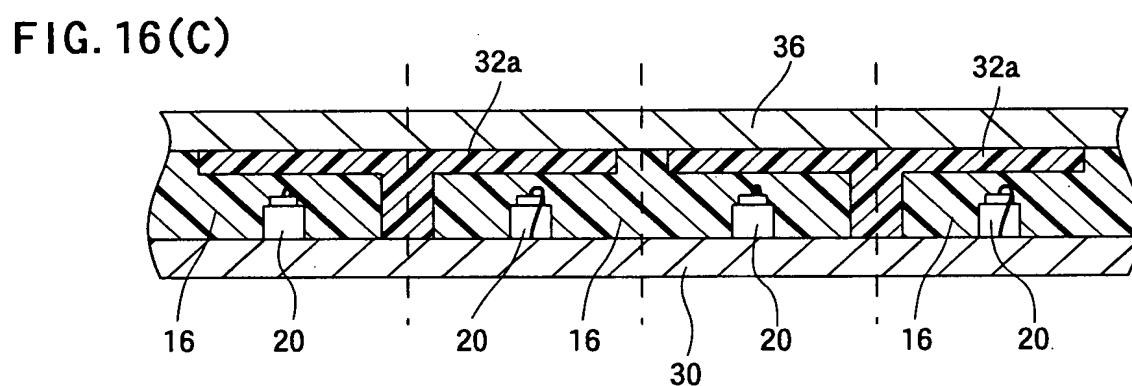
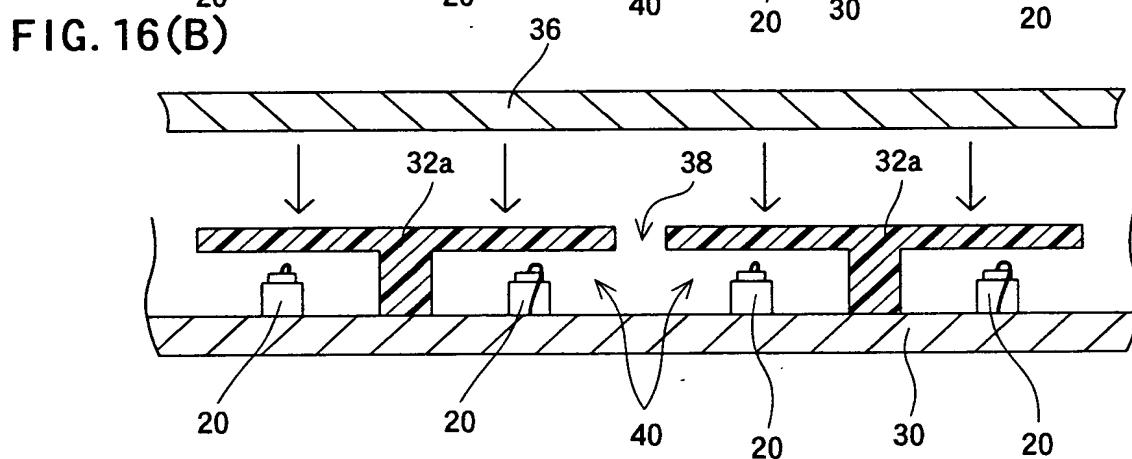
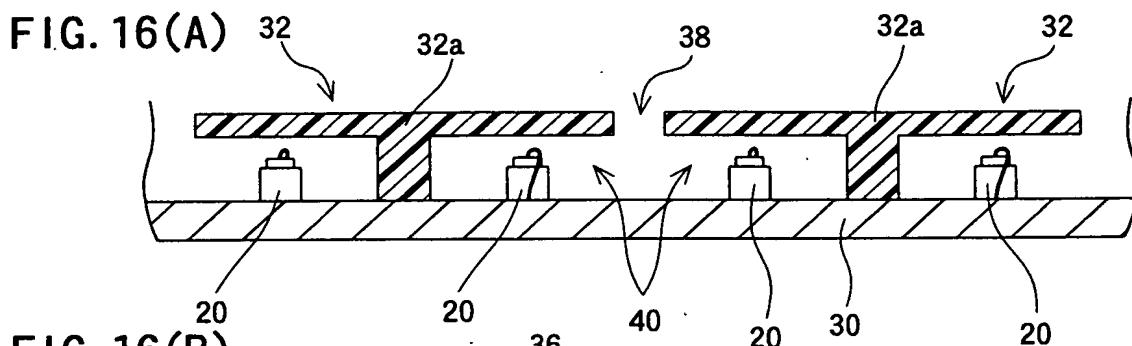


FIG. 17(A)

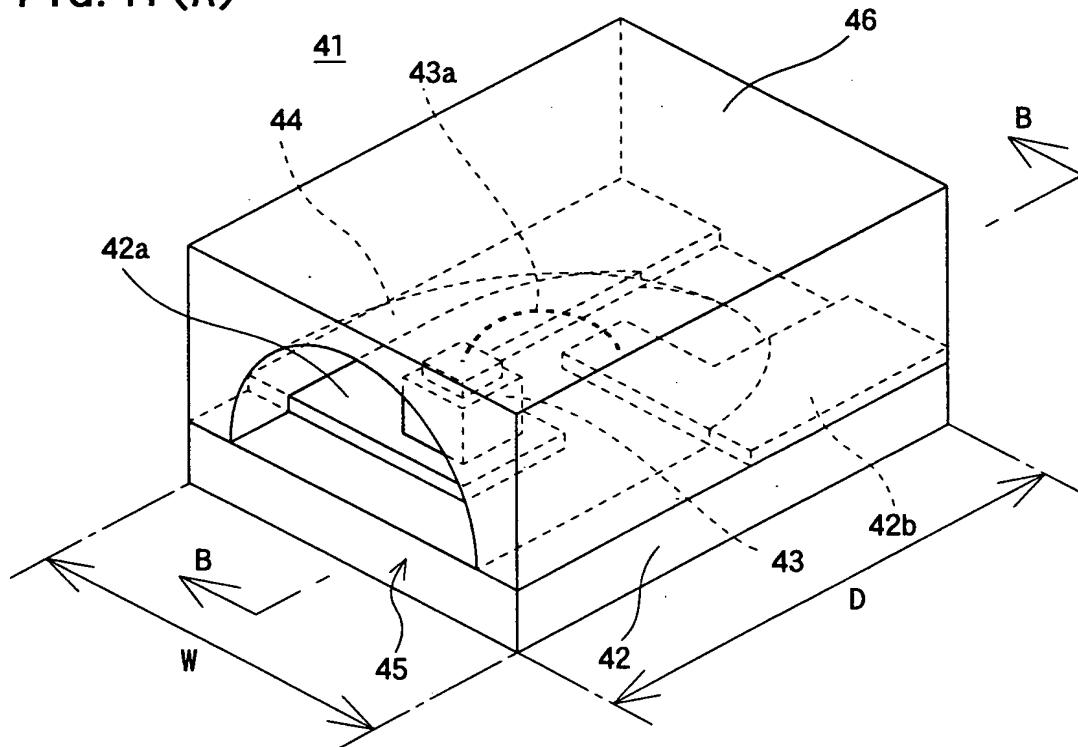


FIG. 17(B)

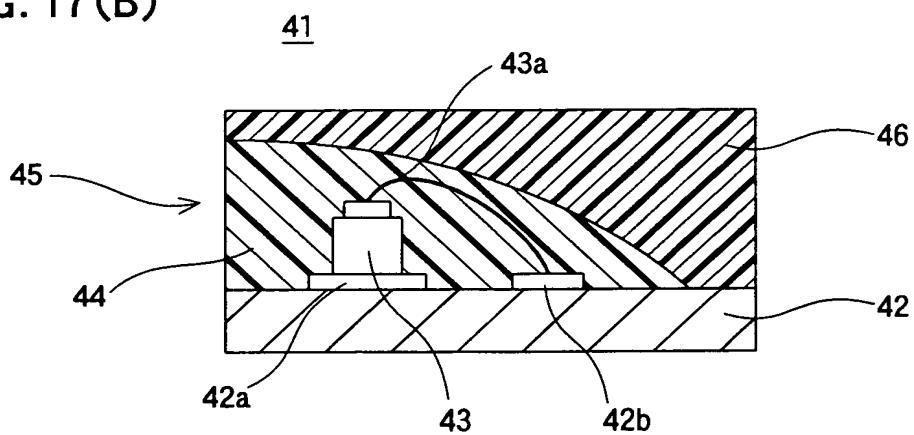


FIG. 18(A)

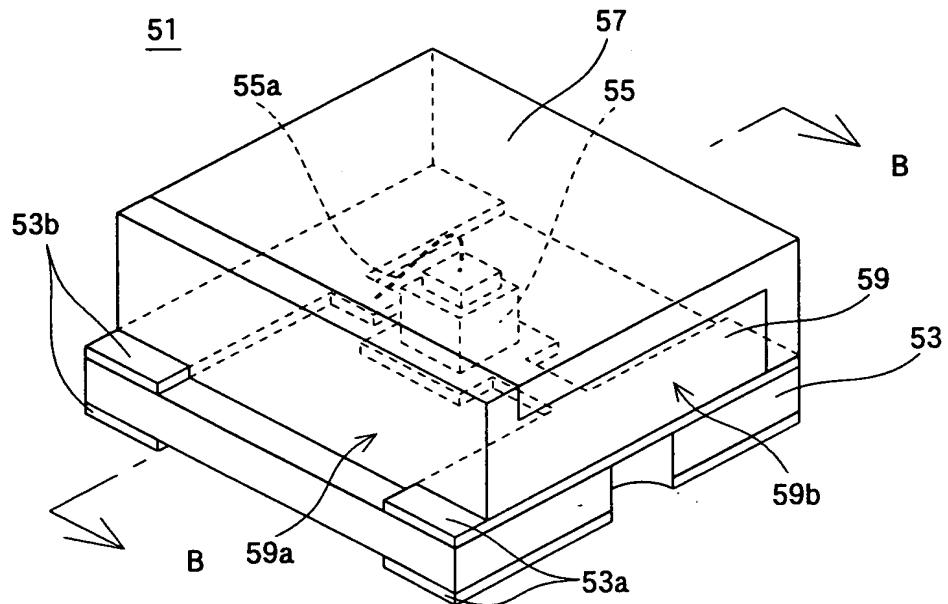


FIG. 18(B)

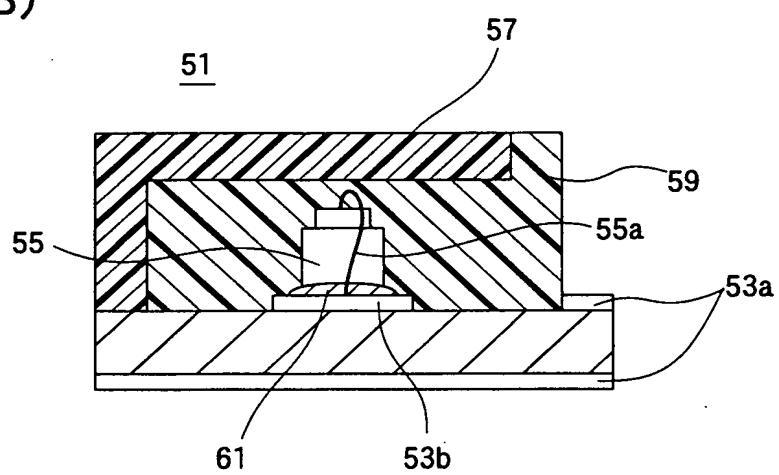


FIG. 19(A)

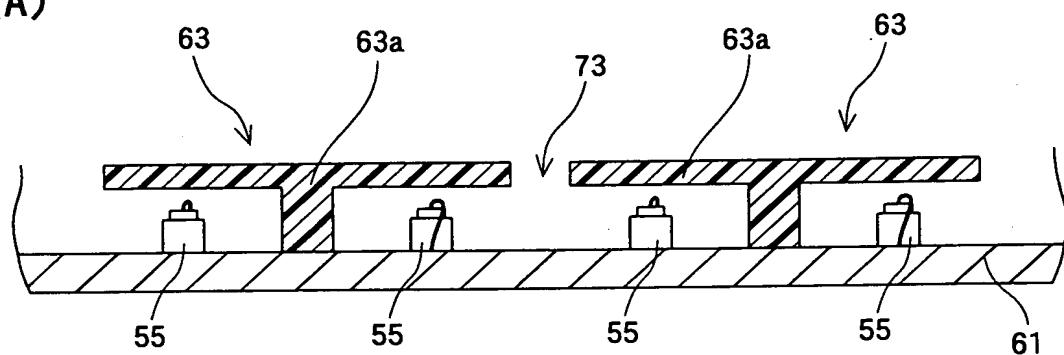


FIG. 19(B)

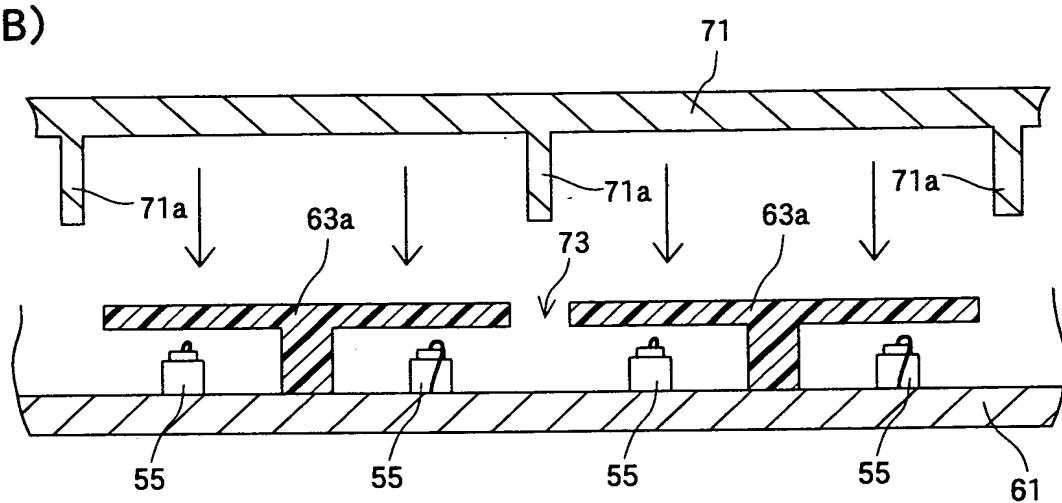


FIG. 19(C)

